



SiC SCHOTTKY DIODE TYPE 2x25A

Features

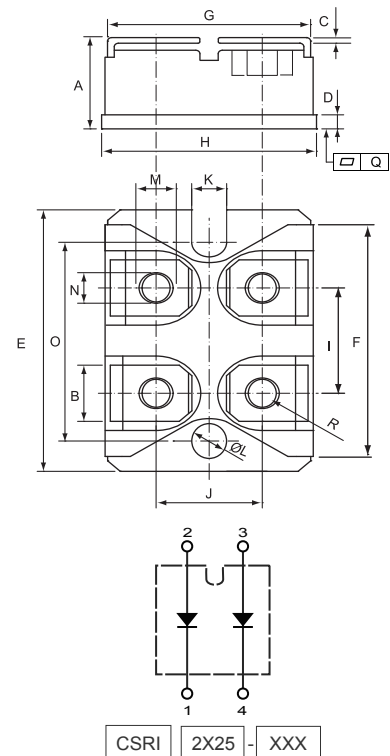
- High surge current capable
- Zero reverse recovery current
- High bandwidth
- Isolation type package
- Temperature Independent Switching Behavior
- VDC 1200 V
- I<sub>F</sub> (T<sub>c</sub><135°C) 2×25 A

Benefits

- Unipolar rectifier
- Zero switching loss
- Higher efficiency
- Smaller heat sink
- Parallel devices without thermal runaway

Applications

- Motor drives
- Switch mode power supplies
- Ev chargers
- Solar inverters
- Welding equipment
- Power factor correction
- Diode snubber
- Automotive
- Induction heating



Maximum Ratings

Operating Junction Temperature : - 55 °C to +175 °C

Storage Temperature : - 55 °C to +175 °C

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum DC Blocking Voltage
CSRI2×25-120	1200V	1200V

Maximum Rating	Symbol	Conditions	Value	Unit
Continuous forward current (per leg)	I <sub>F</sub>	T <sub>C</sub> =135 °C	25	A
Surge non-repetitive forward current sine halfwave (per leg)	I <sub>FSM</sub>	T <sub>C</sub> =25 °C, t <sub>p</sub> =8.3 ms	200	
		T <sub>C</sub> =150 °C, t <sub>p</sub> =8.3 ms	125	
Non-repetitive peak forward current (per leg)	I <sub>F,max</sub>	T <sub>C</sub> =25 °C, t <sub>p</sub> =10 μs	800	
		T <sub>C</sub> =150 °C, t <sub>p</sub> =10 μs	500	
Repetitive peak reverse voltage	V <sub>RRM</sub>	T <sub>J</sub> =25 °C	1200	V
Isolation voltage	V <sub>iso</sub>	50/60 Hz, RMS I <sub>ISOL</sub> 1 ≤ mA	2500	V
Mounting torque		M4 Screw	1.3	N-m

	DIMENSIONS			
	INCHES		MM	
	MIN	MAX	MIN	MAX
A	0.460	0.483	11.68	12.28
B	0.307	0.323	7.80	8.20
C	0.030	0.033	0.75	0.85
D	0.071	0.081	1.80	2.05
E	1.488	1.504	37.80	38.20
F	1.248	1.260	31.70	32.00
G	0.917	0.957	23.30	24.30
H	0.996	1.008	25.30	25.60
I	0.579	0.602	14.70	15.30
J	0.492	0.516	12.50	13.10
K	-	0.169	-	4.30
L	-	0.169	-	4.30
M	0.181	0.197	4.60	5.00
N	0.165	0.181	4.20	4.60
O	1.181	1.197	30.00	30.40
Q	-0.002	0.004	-0.05	0.10
R	M4*8			



**Electrical Characteristics**, at  $T_j=25\text{ }^\circ\text{C}$ , unless otherwise specified. (per leg)

Static Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	
DC blocking voltage	$V_{DC}$		1,200	-	-	V
Diode forward voltage	$V_F$	$I_F=25\text{A}, T_j=25\text{ }^\circ\text{C}$	-	1.6	1.8	
		$I_F=25\text{A}, T_j=175\text{ }^\circ\text{C}$	-	2.4	2.9	
Reverse current	$I_R$	$V_R=1,200\text{V}, T_j=25\text{ }^\circ\text{C}$	-	2.2	109	$\mu\text{A}$
		$V_R=1,200\text{V}, T_j=175\text{ }^\circ\text{C}$	-	140	1,400	

**AC Characteristics** (per leg)

Static Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	
Total capacitive charge	$Q_{rr}$	$V_R=1,200\text{V}, T_j=25\text{ }^\circ\text{C}$	-	72	-	nC
Total capacitance	C	$V_R=0\text{V}, f=1\text{ MHz}$ $T_j=25\text{ }^\circ\text{C}$	-	1,390	-	pF
		$V_R=600\text{V}, f=1\text{ MHz}$ $T_j=25\text{ }^\circ\text{C}$	-	138	-	
		$V_R=1,000\text{V}, f=1\text{ MHz}$ $T_j=25\text{ }^\circ\text{C}$	-	129	-	

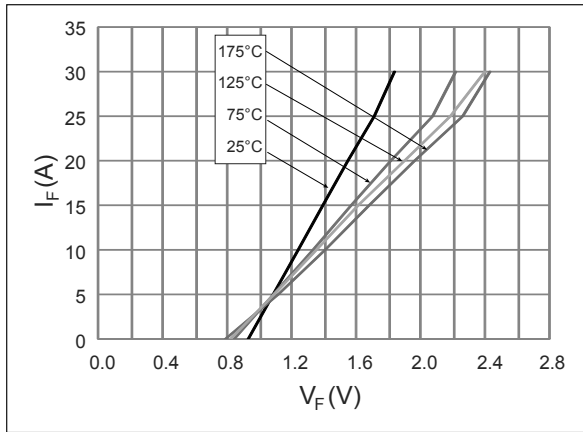
**Thermal Characteristics** (per leg)

Static Characteristics	Symbol	Values	Unit
		typ.	
Thermal resistance from junction to case	$R_{\theta JC}$	0.56	$^\circ\text{C/W}$

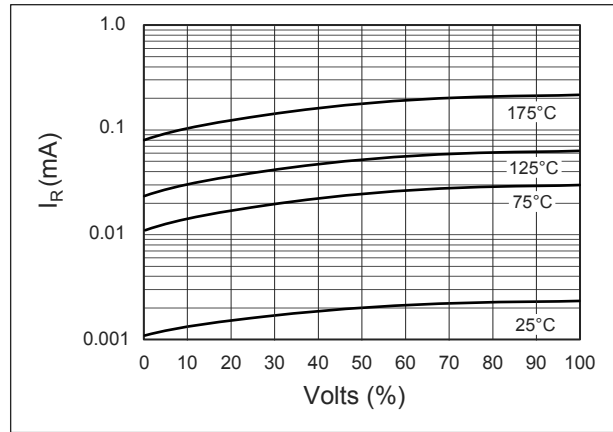


Typical Performance

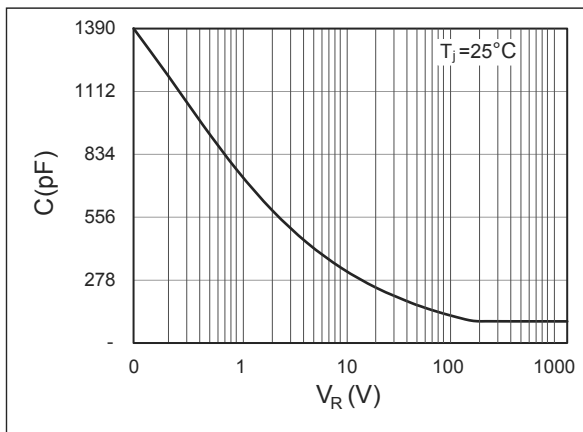
Forward Characteristics (parameterized on  $T_j$ )



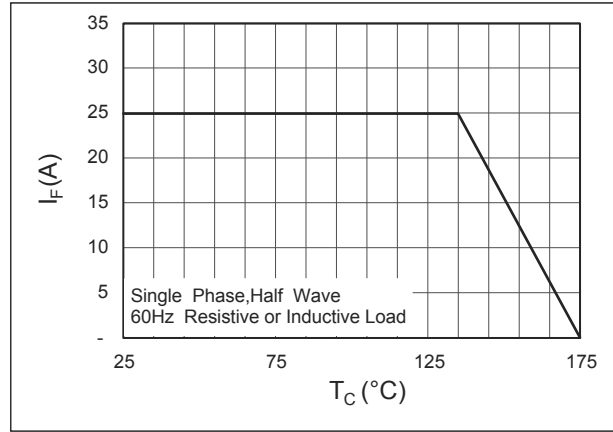
Reverse Characteristics (parameterized on  $T_j$ )



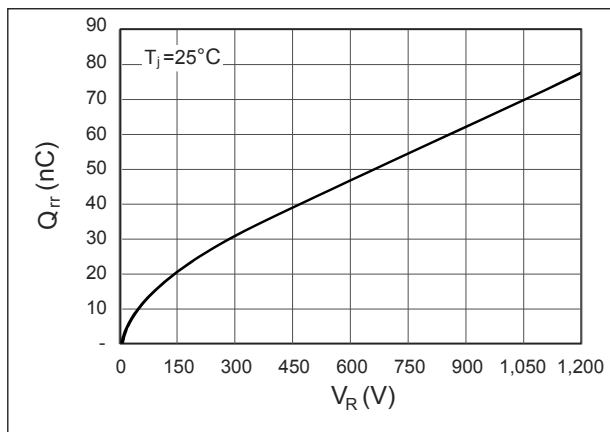
Capacitance



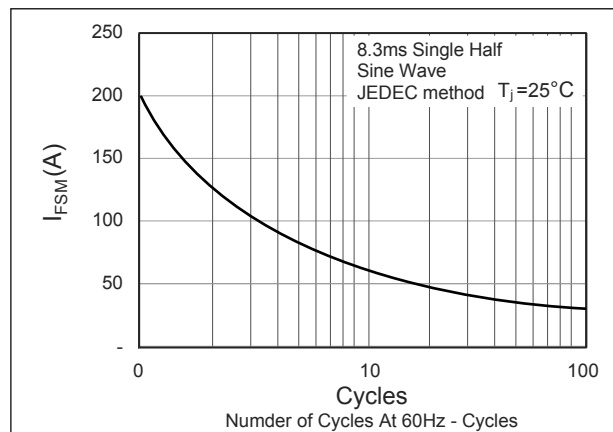
Current Derating



Recovery Charge



Forward Surge Current





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